

### Product Summary

| $V_{(BR)DSS}$ | $R_{DS(on)MAX}$ | $I_D$ |
|---------------|-----------------|-------|
| 150V          | 19mΩ@10V        | 60A   |
|               | 22mΩ@6V         |       |

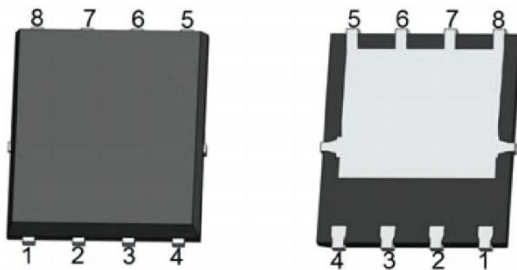
### Feature

- Advanced trench cell design
- Excellent package for heat dissipation
- High density cell design for low  $R_{DS(ON)}$
- Suffix "-Q1" for AEC-Q101

### Application

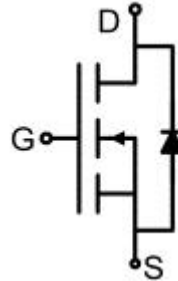
- Power switching application
- Uninterruptible power supply
- DC-DC convertor

### Package

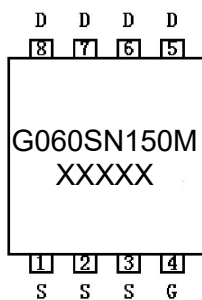


PDFN5\*6-8L

### Circuit diagram



### Marking



### Absolute maximum ratings ( $T_A=25^\circ\text{C}$ unless otherwise noted)

| Parameter  | Symbol                     | Value      | Unit                      |
|--|----------------------------|------------|---------------------------|
| Drain-Source Voltage                                       | $V_{DS}$                   | 150        | V                         |
| Gate-Source Voltage  | $V_{GS}$                   | $\pm 25$   | V                         |
| Continuous Drain Current ( $T_C=25^\circ\text{C}$ )        | $I_D$                      | 60         | A                         |
| Continuous Drain Current ( $T_C=100^\circ\text{C}$ )       | $I_{D(100^\circ\text{C})}$ | 38         | A                         |
| Pulsed Drain Current <sup>1)</sup>                         | $I_{DM}$                   | 120        | A                         |
| Power Dissipation <sup>2)</sup> ( $T_C=25^\circ\text{C}$ ) | $P_D$                      | 125        | W                         |
| Thermal Resistance Junction to Case                        | $R_{\theta JC}$            | 1          | $^\circ\text{C}/\text{W}$ |
| Operating Junction Temperature                             | $T_J$                      | -55 ~ +150 | $^\circ\text{C}$          |
| Storage Temperature  | $T_{STG}$                  | -55 ~ +150 | $^\circ\text{C}$          |

### Electrical characteristics ( $T_J=25^\circ\text{C}$ , unless otherwise noted)

| Parameter                                   | Symbol        | Test Condition  | Min. | Typ. | Max.      | Unit          |
|---|---------------|---|------|------|-----------|---------------|
| <b>Static Characteristics</b>               |               |   |      |      |           |               |
| Drain-source breakdown voltage              | $V_{(BR)DSS}$ | $V_{GS}=0\text{V}, I_D=250\mu\text{A}$                                    | 150  |      |           | V             |
| Zero gate voltage drain current             | $I_{DSS}$     | $V_{DS}=150\text{V}, V_{GS}=0\text{V}$                                    |      |      | 1         | $\mu\text{A}$ |
| Gate-body leakage current                   | $I_{GSS}$     | $V_{DS}=0\text{V}, V_{GS}=\pm 25\text{V}$                                 |      |      | $\pm 100$ | nA            |
| Gate threshold voltage                      | $V_{GS(th)}$  | $V_{DS}=V_{GS}, I_D=250\mu\text{A}$                                       | 2    |      | 4         | V             |
| Drain-source on-resistance                  | $R_{DS(on)}$  | $V_{GS}=10\text{V}, I_D=20\text{A}$                                       |      | 13   | 19        | m $\Omega$    |
|   |               | $V_{GS}=6\text{V}, I_D=10\text{A}$  |      | 15   | 22        |               |
| <b>Dynamic characteristics<sup>3)</sup></b> |               |   |      |      |           |               |
| Input Capacitance                           | $C_{iss}$     | $V_{DS}=75\text{V}, V_{GS}=0\text{V}, f=1\text{MHz}$                      |      | 2100 |           | pF            |
| Output Capacitance                          | $C_{oss}$     |   |      | 160  |           |               |
| Reverse Transfer Capacitance                | $C_{rss}$     |   |      | 5    |           |               |
| Total Gate Charge                           | $Q_g$         | $V_{DS}=75\text{V}, V_{GS}=10\text{V}, I_D=20\text{A}$                    |      | 25   |           | nC            |
| Gate-Source Charge                          | $Q_{gs}$      |   |      | 10   |           |               |
| Gate-Drain Charge                           | $Q_{gd}$      |   |      | 8    |           |               |
| Turn-on delay time                          | $t_{d(on)}$   | $V_{DS}=75\text{V}, V_{GS}=10\text{V}, I_D=20\text{A}$<br>$R_G=4.5\Omega$ |      | 15   |           | nS            |
| Turn-on rise time                           | $t_r$         |   |      | 34   |           |               |
| Turn-off delay time                         | $t_{d(off)}$  |   |      | 30   |           |               |
| Turn-off fall time                          | $t_f$         |   |      | 26   |           |               |
| <b>Source-Drain Diode characteristics</b>   |               |   |      |      |           |               |
| Diode Forward Current                       | $I_S$         |   |      |      | 60        | A             |
| Diode Forward voltage                       | $V_{SD}$      | $V_{GS}=0\text{V}, I_S=20\text{A}$  |      |      | 1.3       | V             |
| Reverse Recovery Time                       | $T_{rr}$      | $I_F=20\text{A}, di/dt=-100\text{A}/\mu\text{s}$                          |      | 86   |           | nS            |
| Reverse Recovery Charge                     | $Q_{rr}$      |   |      | 220  |           | nC            |

Notes:

- 1) Repetitive rating; pulse width limited by max. junction temperature.
- 2)  $P_d$  is based on max. junction temperature, using junction-case thermal resistance.
- 3) Guaranteed by design, not subject to production testing.

## Typical Characteristics

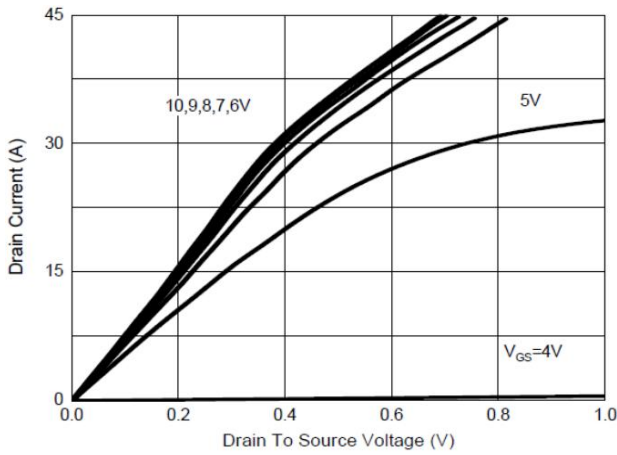


Figure 1. Output Characteristics

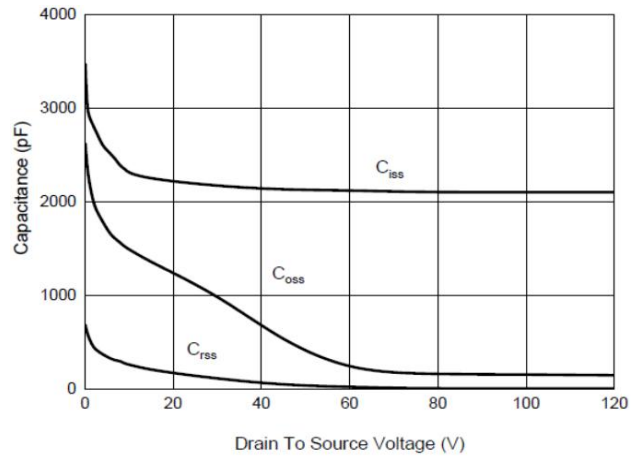


Figure 2. Capacitance Characteristics

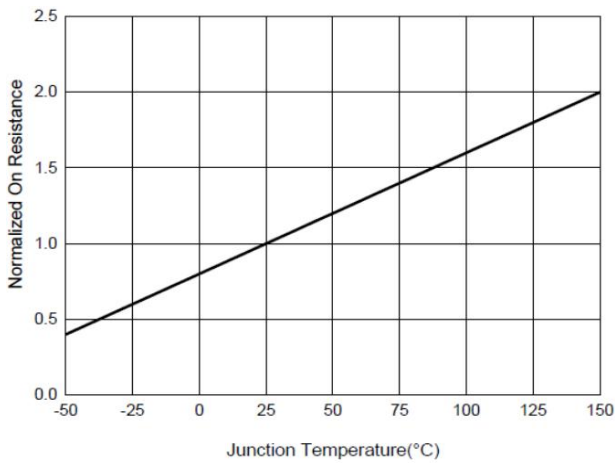


Figure 3. Normalized On-Resistance

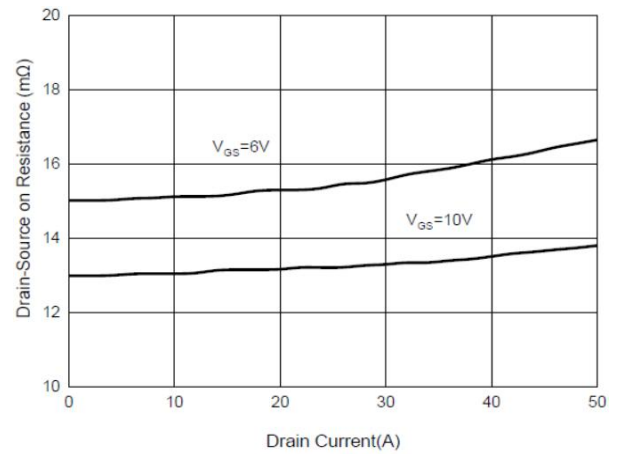


Figure 4. R<sub>DS(on)</sub> VS Drain Current

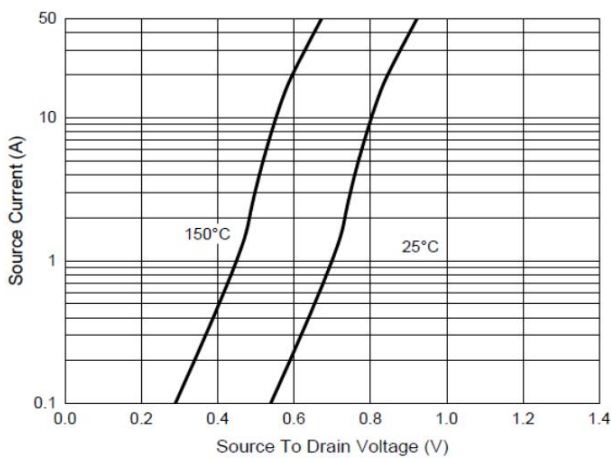


Figure 5. Forward characteristics of reverse diode

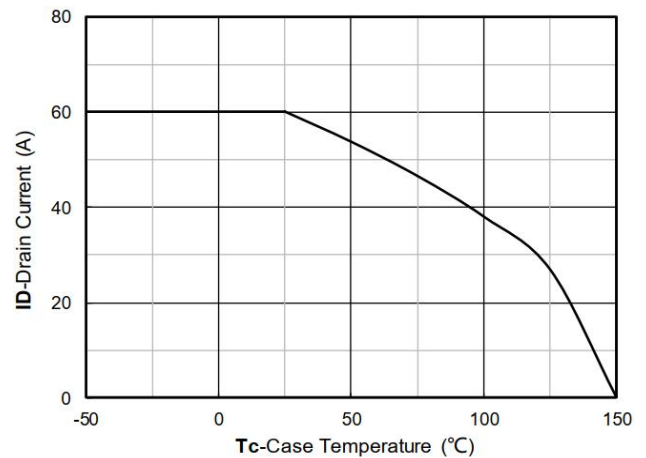


Figure 6. Power dissipation

## Typical Characteristics

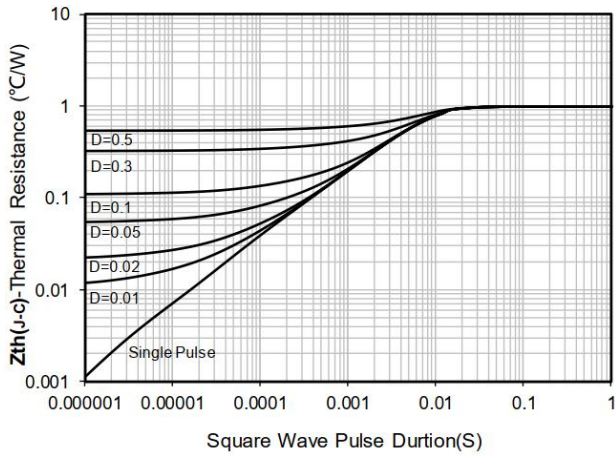


Figure 7. Maximum Transient Thermal Impedance

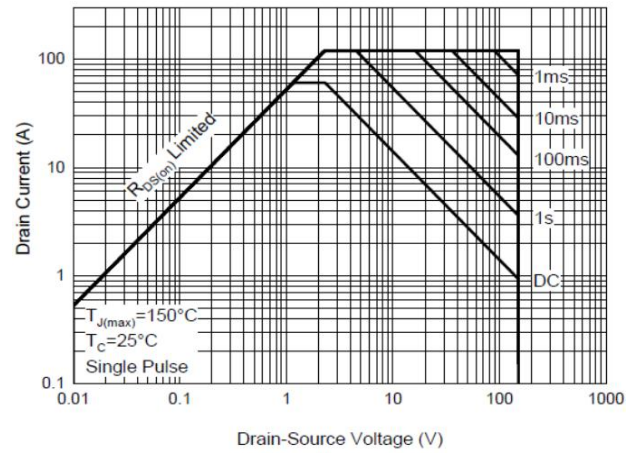
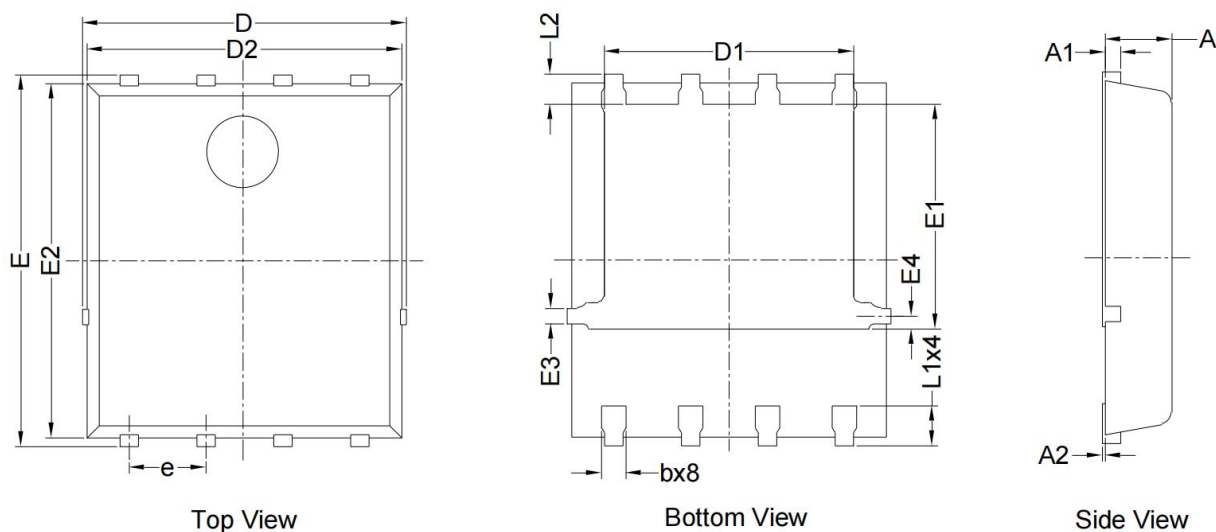


Figure 8. Safe Operation Area

### PDFN5\*6-8L Package Information



| Symbol | Dimensions In Millimeters |       | Dimensions In Inches |       |
|--------|---------------------------|-------|----------------------|-------|
|        | Min.                      | Max.  | Min.                 | Max.  |
| D      | 5.150                     | 5.550 | 0.203                | 0.219 |
| E      | 5.950                     | 6.350 | 0.234                | 0.250 |
| A      | 1.000                     | 1.200 | 0.039                | 0.047 |
| A1     | 0.254 BSC.                |       | 0.010 BSC.           |       |
| A2     | 0.000                     | 0.100 | 0.000                | 0.004 |
| D1     | 3.920                     | 4.320 | 0.154                | 0.170 |
| E1     | 3.520                     | 3.920 | 0.139                | 0.154 |
| D2     | 5.000                     | 5.400 | 0.197                | 0.213 |
| E2     | 5.660                     | 6.060 | 0.223                | 0.239 |
| E3     | 0.254 REF.                |       | 0.010 REF.           |       |
| E4     | 0.210 REF.                |       | 0.008 REF.           |       |
| L1     | 0.560                     | 0.760 | 0.022                | 0.030 |
| L2     | 0.500 BSC.                |       | 0.020 BSC.           |       |
| b      | 0.310                     | 0.510 | 0.012                | 0.020 |
| e      | 1.270 BSC.                |       | 0.050 BSC.           |       |